LM108/208/308

Operational Amplifiers

Description: The 108, 208, 308, 108A, 208A and 308A monolithic operational amplifiers are functionally, electrically and pin-for-pin equivalents to the National LM108, LM208, LM308, LM108A, LM208A and LM308A. They are available in the hermetic TO-99 metal can, dual-in-line, and flat packages.

Distinctive Characteristics: 100% reliability assurance testing including high-temperature bake, temperature cycling, centrifuge and fine leak hermeticity testing in compliance with MIL STD 883.

Electrically tested and optically inspected dice for the assemblers of hybrid products.

FUNCTIONAL DESCRIPTION

These differential input, precision amplifiers provide low input current and offset voltage competitive with FET and chopper stabilized amplifiers. They feature low power consumption over a supply voltage range of ±2V to ±20V. The amplifiers may be frequency compensated with a single external capacitor and are pin-for-pin interchangeable with the 101A/ 201A/301A. The 108A, 208A, and 308A are high performance selections from the 108/208/308 amplifier family.

FUNCTIONAL Frequency Compens	
NON INVERTING A B OUTPUT	INVERTING R1 ON SINVERTING OUTPUT R2 OUTPUT OUTPUT OUTPUT OUTPUT
$C_{t} \ge C_{o} \left(\begin{array}{c} \widetilde{1 - t} \\ \widetilde{C}_{o} = 30 \text{ pF} \end{array} \right)$	1 + R, R, LiC-670

Part Number	Package Type	Temperature Range	Order Number		
	Hermetic DIP	0 to +70°C	LM308D		
LM308	TO-99	0 to +70°C	LM308H		
	Molded DIP	0 to +70°C	LM308N		
	Dice	0 to +70°C	LD308		
	Leadless	0 to +70°C	LM308L		
LM308A	Hermetic DIP	0 to +70°C	LM308AD		
	TO-99	0 to +70°C	LM308AH		
	Molded DIP	0 to +70°C	LM308AN		
	Dice	0 to +70°C	LD308A		
	Leadless	0 to +70°C	LM308AL		
	Hermetic DIP	-25 to +85°C	LM208D		
LM208	TO-99	-25 to +85°C	LM208H		
	Leadless	-25 to +85°C	LM208L		
	Hermetic DIP	-25 to +85°C	LM208AD		
LM208A	TO-99	-25 to +85°C	LM208AH		
LINEOUX	Leadless	-25 to +85°C	LM208AL		
	Hermetic DIP	-55 to +125°C	LM108D		
	TO-99	-55 to +125°C	LM108H		
LM108	Dice	-55 to +125°C	LD108		
	Leadless	-55 to +125°C	LM108L		
	Hermetic DIP	-55 to +125°C	LM108AD		
	TO-99	-55 to +125°C	LM108AH		
LM108A	Dice	-55 to +125°C	LD108A		
	Leadless	-55 to +125°C	LM108AL		

*Also available with burn-in processing. To order add suffix B to part number.

CONNECTION DIAGRAMS - Top Views Leadless Chip-Pak L-20-1								
WOUND THE PART OF								
Molded Dual In-Line P-14-1	Hermetic Dual In-Line D-18-1							
NC 0 1 1 NC COMP A 2 13 NC GUARD 3 12 NC WITH TO 1 NC MINOR THIS MINOR 1 NC M	COMP A 1							
Flat Package F-10-1	Metal Can H-8-1 FREQ_COMP. 8							
NO 1 0 COMP A CO	PHEQUENCY B VY COMP A VI B VY COMP A VI B VY B B							
Notes: 1. On Metal Can, pin 4 is connected to case. 2. On DIP pin 7 is connected to bottom of package. 3. On Flat Package, pin 6 is connected to bottom of pack	•							
	03930B-ANA							

LM108/208/308 · LM108A/208A/308A MAXIMUM RATINGS

Supply Voltage LM108, 208, 108A, 208A, LM308, 308A	±20 V
Internal Power Dissipation (Note 1)	±18 V
Differential Input Current (Note 2)	500 mW
Input Voltage (Note 3)	±10 mA
Output Short-Circuit Duration	±15 V
Operating Temperature Range LM108, 108A LM208, 208A LM308, 308A	Indefinite -55°C to +125°C -25°C to +85°C 0°C to +70°C
Storage Temperature Range	
Lead Temperature (Soldering, 60 sec.)	

ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}C$ unless otherwise specified (see Note 4)

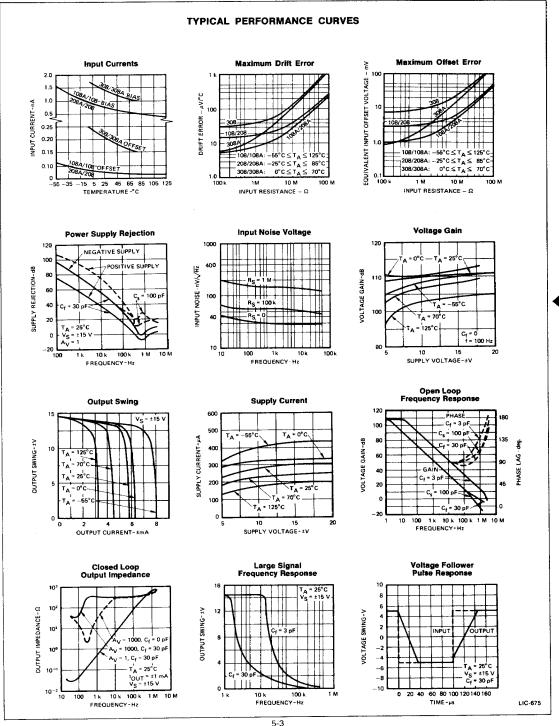
Parameters		LM308				LM308A			LM108 LM208			LM108A LM208A		
	Test Conditions	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Units
Input Offset Voltage			2.0	7.5		0.3	0.5	T	0.7	2.0		0.3	0.5	mV
Input Offset Current			0.2	1.0		0.2	1.0	<u> </u>	0.05	0.2		0.05	0.2	nA
Input Bias Current			1.5	7		1.5	7		0.8	2.0	-	0.8	2.0	nA
Input Resistance		10	40	†	10	40		30	70		30	70		MΩ
Supply Current	V _S = ±20V	1	1					-	0.3	0.6	1	0.3	0.6	1412
	V _S = ±15V		0.3	0.8.		0.3	0.8	†	<u> </u>	-				mA
Large Signal Voltage Gain	$V_S = \pm 15V$ $V_{OUT} = \pm 10V$ $R_L \ge 10k\Omega$	25	300		80	300		50	300		80	300		V/mV
The Following Specifica	tions Apply over t	he Ope	erating	Temp	erature	Rang	es		·	1				
Input Offset Voltage				10			0.73		Ι	3.0	Γ		1.0	mV
Input Offset Current				1.5			1.5			0.4			0.4	nA
Average Temperature Coefficient of Input Offset Voltage			6.0	3.0		1.0	5.0		3.0	15		1.0	5.0	μV/°C
Average Temperature Coefficient of Input Offset Current			2	10		2.0	10		0.5	2.5		0.5	2.5	pA/°C
Input Bias Current				10			10			3.0			3.0	nA
Large Signal Voltage Gain	$V_S = \pm 15V$ $V_{OUT} = \pm 10V$ $R_L \ge 10k\Omega$	15			60			25		0.0	40		0.0	V/mV
Input Voltage Range	V _S = ±15V	± 13.5			± 13.5			± 13.5			±13.5			V
Common Mode Rejection Ratio		80	100		96	110		85	100		96	110		dB
Supply Voltage Rejection Ratio		80	96		96	110	-	80	96		96	110		dB
Output Voltage Swing	$V_S = \pm 15V$ $R_L = 10k\Omega$	± 13	±14		± 13	± 14		± 13	± 14		± 13	±14		V
Supply Current	V _S = ±20V T = T _A Max								0.15	0.4		0.15	0.4	
	V _S = ±15V T = T _A Max		0.6	1.0		0.6	0.8							mA

Notes: 1. Derate Metal Can package at 6.8mW/°C for operation at ambient temperatures above 75°C and the Dual In-Line package at 9mW/°C for operation at ambient temperatures above 95°C.

3. For supply voltages less than ±15V, the maximum input voltage is equal to the supply voltage.

The inputs are shunted with back-to-back diodes for overvoltage protection. Therefore, excessive current will flow if a differential input voltage in excess of 1V is applied between the inputs unless some limiting resistance is used.

Unless otherwise specified, these specifications apply for supply voltages from ±5 to ±20V for the 108, 208, 108A and 208A and from ±5 to ±15V for the 308 and 308A.



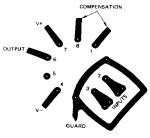
ADDITIONAL APPLICATION INFORMATION

GUARDING

Extra care must be taken in the assembly of printed circuit boards to take full advantage of the low input currents of the 108 amplifier. Boards must be thoroughly cleaned with TCE or alcohol and blown dry with compressed air. After cleaning, the boards should be coated with epoxy or silicone rubber to prevent contamination.

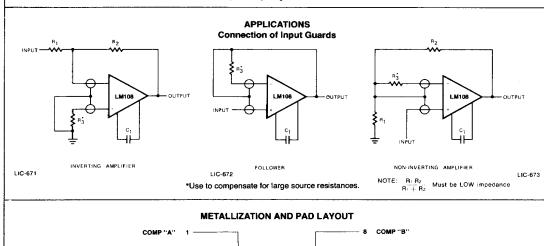
Even with properly cleaned and coated boards, leakage currents may cause trouble at 125°C, particularly since the input pins are adjacent to pins that are at supply potentials. This leakage can be significantly reduced by using guarding to lower the voltage difference between the inputs and adjacent metal runs. Input guarding of the 8-lead TO-99 package is accomplished by using a 10-lead pin circle, with the leads of the device formed so that the holes adjacent to the inputs are empty when it is inserted in the board. The guard, which is a conductive ring surrounding the inputs, is connected to a low-impedance point that is at approximately the same voltage as the inputs. Leakage currents from high-voltage pins are then absorbed by the guard.

The pin configuration of the dual-in-line package is designed to facilitate guarding, since the pins adjacent to the inputs are not used (this is different from the standard 741 and 101A pin configuration.)



BOTTOM VIEW

Board layout for Input Guarding with TO-99 package.



DIE SIZE 0.046" X 0.068"

6 OUTPUT

INPUT (-) 2

INPUT (+) 3 --